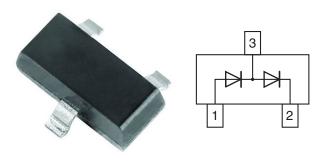


## Vishay Semiconductors

# **Small Signal Switching Diode, Dual**



## **DESIGN SUPPORT TOOLS** click logo to get started



### **MECHANICAL DATA**

Case: SOT-23

Weight: approx. 8.8 mg
Packaging codes / options:

18/10K per 13" reel (8 mm tape), 10K/box 08/3K per 7" reel (8 mm tape), 15K/box

#### **FEATURES**

- · Silicon epitaxial planar diode
- Fast switching dual diode, especially suited for automatic insertion
- AEC-Q101 qualified available
- Base P/N-E3 RoHS-compliant, commercial grade



- Base P/N-HE3 RoHS-compliant, AEC-Q101 qualified
- Material categorization: for definitions of compliance please see <u>www.vishay.com/doc?99912</u>

| PARTS TABLE |                                    |                       |              |               |  |
|-------------|------------------------------------|-----------------------|--------------|---------------|--|
| PART        | ORDERING CODE                      | CIRCUIT CONFIGURATION | TYPE MARKING | REMARKS       |  |
| MMBD7000    | MMBD7000-E3-08 or MMBD7000-E3-18   | Dual serial           | M5C          | Tape and reel |  |
|             | MMBD7000-HE3-08 or MMBD7000-HE3-18 | Duai Seriai           | IVISC        |               |  |

| <b>ABSOLUTE MAXIMUM RATINGS</b> (T <sub>amb</sub> = 25 °C, unless otherwise specified) |                    |                  |       |      |
|--|--------------------|------------------|-------|------|
| PARAMETER  | TEST CONDITION     | SYMBOL           | VALUE | UNIT |
| Reverse voltage  |                    | $V_R$            | 100   | V    |
| Forward current (continuous)   |                    | I <sub>F</sub>   | 200   | mA   |
| Non-repetitive peak forward current  | t = 1 s            | I <sub>FSM</sub> | 500   | mA   |
| Dower dissipation on ED 5 hoard  |                    | P <sub>tot</sub> | 225   | mW   |
| Power dissipation on FR-5 board  | Derate above 25 °C | P <sub>tot</sub> | 1.8   | mW/K |
| Total device discinstics on alumino substrate  |                    | P <sub>tot</sub> | 300   | mW   |
| Total device dissipation on alumina substrate  | Derate above 25 °C | P <sub>tot</sub> | 2.4   | mW/K |

| THERMAL CHARACTERISTICS (T <sub>amb</sub> = 25 °C, unless otherwise specified) |                |                       |             |      |  |
|--|----------------|-----------------------|-------------|------|--|
| PARAMETER  | TEST CONDITION | SYMBOL                | VALUE       | UNIT |  |
| Turnical thousand vaciations a junction to embient air                         |                | R <sub>thJA</sub> (1) | 417         | K/W  |  |
| Typical thermal resistance, junction to ambient air                            |                | R <sub>thJA</sub> (2) | 556         | K/W  |  |
| Maximum junction temperature   |                | Tj                    | 150         | °C   |  |
| Storage temperature range  |                | T <sub>stg</sub>      | -55 to +150 | °C   |  |
| Operating temperature range  |                | T <sub>op</sub>       | -55 to +150 | °C   |  |

#### Notes

(1) Device on alumina substrate

(2) On FR-5 board

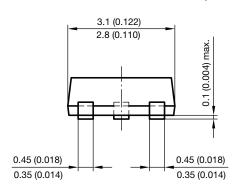


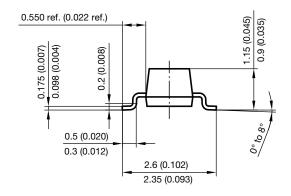
### www.vishay.com

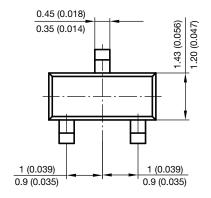
# Vishay Semiconductors

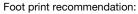
| <b>ELECTRICAL CHARACTERISTICS</b> (T <sub>amb</sub> = 25 °C, unless otherwise specified) |  |                   |      |      |      |      |
|--|--|-------------------|------|------|------|------|
| PARAMETER  | TEST CONDITION   | SYMBOL            | MIN. | TYP. | MAX. | UNIT |
| Reverse breakdown voltage  | I <sub>R</sub> = 100 μA  | V <sub>(BR)</sub> | 100  |      |      | V    |
|  | V <sub>R</sub> = 50 V  | I <sub>R</sub>    |      |      | 1000 | nA   |
| Leakage current  | V <sub>R</sub> = 100 V   | I <sub>R</sub>    |      |      | 3    | μΑ   |
|  | $V_R = 50 \text{ V}, T_j = 125 ^{\circ}\text{C}$                       | I <sub>R</sub>    |      |      | 100  | μA   |
|  | I <sub>F</sub> = 1 mA  | V <sub>F</sub>    | 0.55 |      | 0.70 | V    |
| Forward voltage  | I <sub>F</sub> = 10 mA   | $V_{F}$           | 0.67 |      | 0.82 | V    |
|  | I <sub>F</sub> = 100 mA  | V <sub>F</sub>    | 0.75 |      | 1.10 | V    |
| Diode capacitance  | $V_R = 0$ , $f = 1 MHz$  | C <sub>D</sub>    |      |      | 1.5  | pF   |
| Reverse recovery time  | $I_F = I_R = 10 \text{ mA}, i_R = 1 \text{ mA},$<br>$R_L = 100 \Omega$ | t <sub>rr</sub>   |      |      | 4    | ns   |

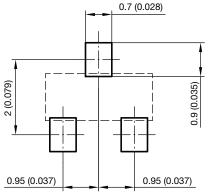
## PACKAGE DIMENSIONS in millimeters (inches): SOT-23











Document no.: 6.541-5014.01-4 Rev. 8 - Date: 23.Sept.2009



# **Legal Disclaimer Notice**

Vishay

## **Disclaimer**

ALL PRODUCT, PRODUCT SPECIFICATIONS AND DATA ARE SUBJECT TO CHANGE WITHOUT NOTICE TO IMPROVE RELIABILITY, FUNCTION OR DESIGN OR OTHERWISE.

Vishay Intertechnology, Inc., its affiliates, agents, and employees, and all persons acting on its or their behalf (collectively, "Vishay"), disclaim any and all liability for any errors, inaccuracies or incompleteness contained in any datasheet or in any other disclosure relating to any product.

Vishay makes no warranty, representation or guarantee regarding the suitability of the products for any particular purpose or the continuing production of any product. To the maximum extent permitted by applicable law, Vishay disclaims (i) any and all liability arising out of the application or use of any product, (ii) any and all liability, including without limitation special, consequential or incidental damages, and (iii) any and all implied warranties, including warranties of fitness for particular purpose, non-infringement and merchantability.

Statements regarding the suitability of products for certain types of applications are based on Vishay's knowledge of typical requirements that are often placed on Vishay products in generic applications. Such statements are not binding statements about the suitability of products for a particular application. It is the customer's responsibility to validate that a particular product with the properties described in the product specification is suitable for use in a particular application. Parameters provided in datasheets and / or specifications may vary in different applications and performance may vary over time. All operating parameters, including typical parameters, must be validated for each customer application by the customer's technical experts. Product specifications do not expand or otherwise modify Vishay's terms and conditions of purchase, including but not limited to the warranty expressed therein.

Except as expressly indicated in writing, Vishay products are not designed for use in medical, life-saving, or life-sustaining applications or for any other application in which the failure of the Vishay product could result in personal injury or death. Customers using or selling Vishay products not expressly indicated for use in such applications do so at their own risk. Please contact authorized Vishay personnel to obtain written terms and conditions regarding products designed for such applications.

No license, express or implied, by estoppel or otherwise, to any intellectual property rights is granted by this document or by any conduct of Vishay. Product names and markings noted herein may be trademarks of their respective owners.